








	<h2 style="color: red;">FQD3P50TM</h2> <p>Hersteller-Teilenummer: FQD3P50TM</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET P-CH 500V 2.1A DPAK</p> <p>Datenblätter:  1.FQD3P50TM.pdf  2.FQD3P50TM.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 4811 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQD3P50TM
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET P-CH 500V 2.1A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	4811 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	D-Pak
Verlustleistung (max)	2.5W (Ta), 50W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	2.1A (Tc)
Rds On (Max) @ Id, Vgs	4.9 Ohm @ 1.05A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	23nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	660pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)



















































FQD3P50TM ist neu im Original, Suche FQD3P50TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQD3P50TM Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQD3P50TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQD3P50 FAIRCHI FQD3P50 FAIRCHI</p>	 <p>FQD3P50TM_F085 Fairchild/ON Semiconductor MOSFET P-CH 500V 2.1A DPAK</p>	 <p>FQD3P50TM-F085 AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 2.1A DPAK</p>	 <p>FQD45N03L F F TO-252</p>
 <p>FQD3P50TF Fairchild/ON Semiconductor MOSFET P-CH 500V 2.1A DPAK</p>	 <p>FQD3P50TM-AM002BLT AMI Semiconductor / ON Semiconductor QF -500V 4.9OHM DPAK</p>	 <p>FQD3P50TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 2.1A DPAK</p>	 <p>FQD3P50TF AMI Semiconductor / ON Semiconductor MOSFET P-CH 500V 2.1A DPAK</p>

heiße Teile

Mehr

 FQD3N30TF	 FQD3N30TM	 FQD3N30TM	 FQD3N40TM	 FQD3N40TM
 FQD3N50C	 FQD3N50C/CS	 FQD3N50CTF	 FQD3N50CTF	 FQD3N50CTM
 FQD3N50CTM	 FQD3N60C	 FQD3N60CS	 FQD3N60CTF	 FQD3N60CTM
 FQD3N60CTM_WS	 FQD3N60TF	 FQD3N60TF	 FQD3N60TM	 FQD3N60TM
 FQD3P20TF	 FQD3P20TF	 FQD3P50TF	 FQD3P50TF	 FQD3P50TM
 FQD4N20L	 FQD4N20LTF	 FQD4N20LTF	 FQD4N20TF	 FQD4N20TF
 FQD4N20TM	 FQD4N20TM	 FQD4N25TM	 FQD4N25TM	 FQD4N50S
 FQD4N50T	 FQD4N50TF	 FQD4N50TF	 FQD4N50TM	 FQD4N50TM
 FQD4N60C	 FQD4N60CTM	 FQD4N65C	 FQD4P25TM	 FQD4P25TM
 FQD5N15TF	 FQD5N15TF	 FQD5N15TM	 FQD5N15TM	 FQD5N20L

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